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Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

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HA17431 Series

Shunt Regulator

ADE-204-049A (Z)

Rev.1
Sep. 2002

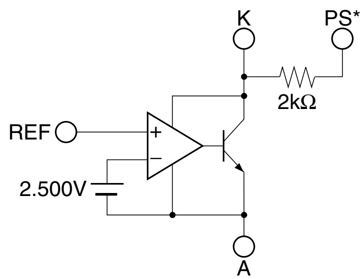
Description

The HA17431 series is temperature-compensated variable shunt regulators. The main application of these products is in voltage regulators that provide a variable output voltage. The on-chip high-precision reference voltage source can provide ±1% accuracy in the V versions, which have a V_{KA} max of 16 volts. The HA17431VLP, which is provided in the MPAK-5 package, is designed for use in switching mode power supplies. It provides a built-in photocoupler bypass resistor for the PS pin, and an error amplifier can be easily constructed on the supply side.

Features

- The V versions provide 2.500 V ±1% at Ta = 25°C
- The HA17431VLP includes a photocoupler bypass resistor (2 kΩ)
- The reference voltage has a low temperature coefficient
- The MPAK-5(5-pin), MPAK(3-pin) and UPAK miniature packages are optimal for use on high mounting density circuit boards
- Car use is provided

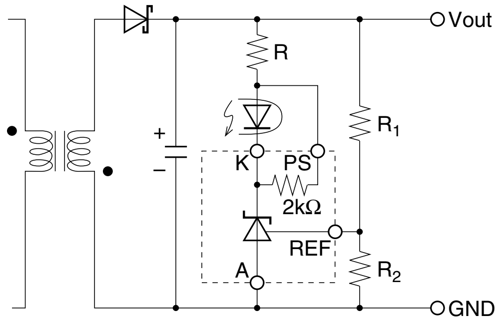
Block Diagram



Note: * The PS pin is only provided by the HA17431VLP.

Application Circuit Example

Switching power supply secondary-side error amplification circuit



HA17431VLP

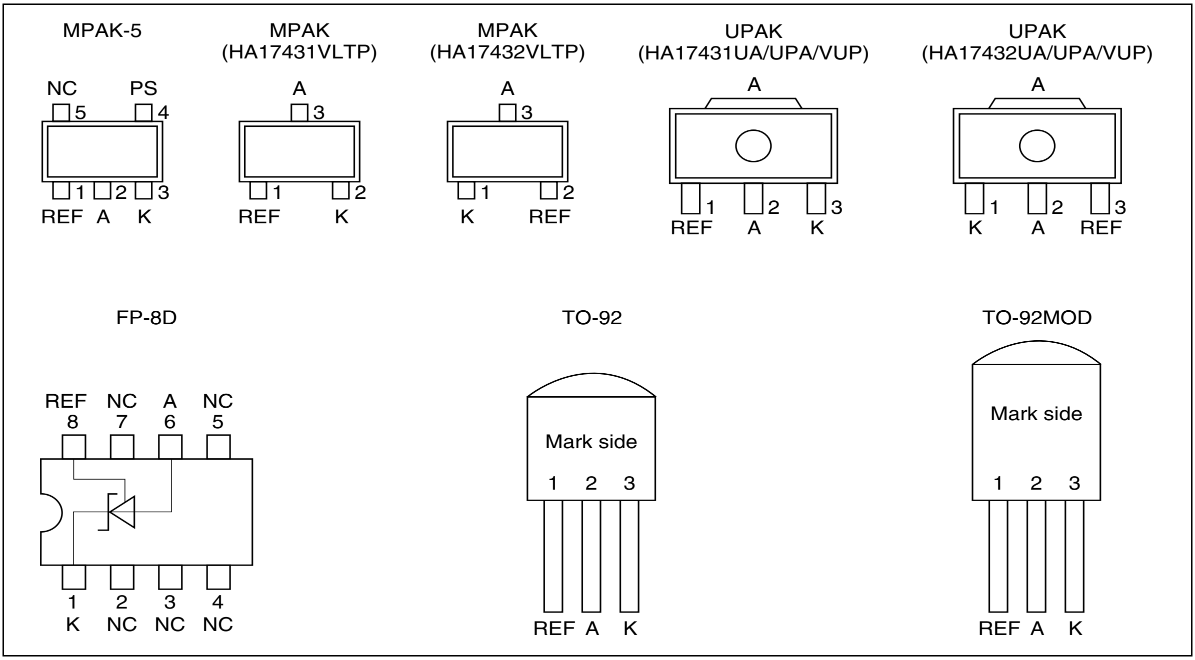
Ordering Information

Item		Version: V Version	Version: A Version	Version: Normal Version	Package	Operating Temperature Range
Reference voltage (at 25°C)	Accuracy	±1%	±2.2%	±4%		
	Max	2.525 V	2.550 V	2.595 V		
	Typ	2.500 V	2.495 V	2.495 V		
	Min	2.475 V	2.440 V	2.395 V		
Cathode voltage		16 V max	40 V max	40 V max		
Cathode current		50 mA max	150 mA max	150 mA max		
Car use		HA17431VPJ			TO-92	–40 to +85°C
			HA17431PNAJ			
			HA17431PAJ		TO-92MOD	
				HA17431PJ		
			HA17431FPAJ		FP-8D	
				HA17431FPJ		

Ordering Information (cont.)

Item	V Version	A Version	Normal Version	Package	Operating Temperature Range
Industrial use	HA17431VLTP			MPAK	–20 to +85°C
	HA17432VLTP				
	HA17431VLP			MPAK-5	
	HA17431VP			TO-92	
		HA17431PNA			
	HA17431VUP			UPAK	
		HA17431UPA			
	HA17432VUP				
		HA17432UPA			
		HA17431PA		TO-92MOD	
			HA17431P		
		HA17431FPA		FP-8D	
			HA17431FP		
Commercial use		HA17431UA		UPAK	
		HA17432UA			

Pin Arrangement



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	HA17431VLP	HA17431VP	HA17431VPJ	Unit	Notes
Cathode voltage	V_{KA}	16	16	16	V	1
PS term. voltage	V_{PS}	V_{KA} to 16	—	—	V	1,2,3
Continuous cathode current	I_K	–50 to +50	–50 to +50	–50 to +50	mA	
Reference input current	Iref	–0.05 to +10	–0.05 to +10	–0.05 to +10	mA	
Power dissipation	P_T	150 *4	500 *5	500 *5	mW	4, 5
Operating temperature range	Topr	–20 to +85	–20 to +85	–40 to +85	°C	
Storage temperature	Tstg	–55 to +150	–55 to +150	–55 to +150		°C

Item	Symbol	HA17431VUP/HA17432VUP	HA17431VLTP/HA17432VLTP	Unit	Notes
Cathode voltage	V_{KA}	16	16	V	1
PS term. voltage	V_{PS}	—	—	V	1,2,3
Continuous cathode current	I_K	–50 to +50	–50 to +50	mA	
Reference input current	Iref	–0.05 to +10	–0.05 to +10	mA	
Power dissipation	P_T	800 *8	150 *4	mW	4, 8
Operating temperature range	Topr	–20 to +85	–20 to +85	°C	
Storage temperature	Tstg	–55 to +150	–55 to +150	°C	

Item	Symbol	HA17431PNA	HA17431P/PA	HA17431FP/FPA	HA17431UA/UPA/ HA17432UA/UPA	Unit	Notes
Cathode voltage	V_{KA}	40	40	40	40	V	1
Continuous cathode current	I_K	–100 to +150	–100 to +150	–100 to +150	–100 to +150	mA	
Reference input current	Iref	–0.05 to +10	–0.05 to +10	–0.05 to +10	–0.05 to +10	mA	
Power dissipation	P_T	500 *5	800 *6	500 *7	800 *8	mW	5,6,7,8
Operating temperature range	Topr	–20 to +85	–20 to +85	–20 to +85	–20 to +85	°C	
Storage temperature	Tstg	–55 to +150	–55 to +150	–55 to +125	–55 to +150	°C	

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Absolute Maximum Ratings (cont.)

(Ta = 25°C)

Item	Symbol	HA17431PNAJ	HA17431PJ/PAJ	HA17431FPJ/FPAJ	Unit	Notes
Cathode voltage	V_{KA}	40	40	40	V	1
Continuous cathode current	I_K	–100 to +150	–100 to +150	–100 to +150	mA	
Reference input current	Iref	–0.05 to +10	–0.05 to +10	–0.05 to +10	mA	
Power dissipation	P_T	500 *5	800 *6	500 *7	mW	5,6,7
Operating temperature range	Topr	–40 to +85	–40 to +85	–40 to +85	°C	
Storage temperature	Tstg	–55 to +150	–55 to +150	–55 to +125	°C	

Notes:
1. Voltages are referenced to anode.
2. The PS pin is only provided by the HA17431VLP.
3. The PS pin voltage must not fall below the cathode voltage. If the PS pin is not used, the PS pin is recommended to be connected with the cathode.
4. Ta ≤ 25°C. If Ta > 25°C, derate by 1.2 mW/°C.
5. Ta ≤ 25°C. If Ta > 25°C, derate by 4.0 mW/°C.
6. Ta ≤ 25°C. If Ta > 25°C, derate by 6.4 mW/°C.
7. 50 mm × 50 mm × 1.5mmt glass epoxy board(5% wiring density), Ta ≤ 25°C. If Ta > 25°C, derate by 5 mW/°C.
8. 15 mm × 25 mm × 0.7mmt alumina ceramic board,Ta ≤ 25°C. If Ta > 25°C, derate by 6.4 mW/°C.

Electrical Characteristics

HA17431VLP/VP/VPJ/VUP/VLTP, HA17432VUP/VLTP

(Ta = 25°C, I_K = 10 mA)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions	Notes
Reference voltage	Vref	2.475	2.500	2.525	V	V_{KA} = Vref	
Reference voltage temperature deviation	Vref(dev)	—	10	—	mV	V_{KA} = Vref, Ta = –20°C to +85°C	1
Reference voltage temperature coefficient	ΔVref/ΔTa	—	±30	—	ppm/°C	V_{KA} = Vref, 0°C to 50°C gradient	
Reference voltage regulation	ΔVref/ΔV_{KA}	—	2.0	3.7	mV/V	V_{KA} = Vref to 16 V	
Reference input current	Iref	—	2	6	μA	R_1 = 10 kΩ, R_2 = ∞	
Reference current temperature deviation	Iref(dev)	—	0.5	—	μA	R_1 = 10 kΩ, R_2 = ∞, Ta = –20°C to +85°C	
Minimum cathode current	Imin	—	0.4	1.0	mA	V_{KA} = Vref	2
Off state cathode current	Ioff	—	0.001	1.0	μA	V_{KA} = 16 V, Vref = 0 V	
Dynamic impedance	Z_{KA}	—	0.2	0.5	Ω	V_{KA} = Vref, I_K = 1 mA to 50 mA	
Bypass resistance	R_{PS}	1.6	2.0	2.4	kΩ	I_{PS} = 1 mA	3
Bypass resistance temperature coefficient	ΔR_{PS}/ΔTa	—	+2000	—	ppm/°C	I_{PS} = 1 mA, 0°C to 50°C gradient	3

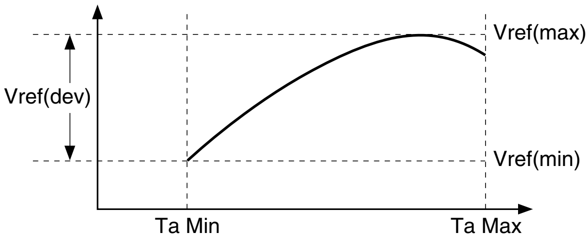
Electrical Characteristics (cont.)

HA17431PJ/PAJ/FPJ/FPAJ/P/PA/UA/UPA/FP/FPA/PNA/PNAJ, HA17432UA/UPA

(Ta = 25°C, I_K = 10 mA)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions		Notes
Reference voltage	Vref	2.440	2.495	2.550	V	V_{KA} = Vref		A
		2.395	2.495	2.595				Normal
Reference voltage temperature deviation	Vref(dev)	—	11	(30)	mV	V_{KA} = Vref	Ta = –20°C to +85°C	1, 4
		—	5	(17)			Ta = 0°C to +70°C	1, 4
Reference voltage regulation	ΔVref/ΔV_{KA}	—	1.4	3.7	mV/V	V_{KA} = Vref to 10 V		
		—	1	2.2		V_{KA} = 10 V to 40 V		
Reference input current	Iref	—	3.8	6	µA	R_1 = 10 kΩ, R_2 = ∞		
Reference current temperature deviation	Iref(dev)	—	0.5	(2.5)	µA	R_1 = 10 kΩ, R_2 = ∞, Ta = 0°C to +70°C		4
Minimum cathode current	Imin	—	0.4	1.0	mA	V_{KA} = Vref		2
Off state cathode current	Ioff	—	0.001	1.0	µA	V_{KA} = 40 V, Vref = 0 V		
Dynamic impedance	Z_{KA}	—	0.2	0.5	Ω	V_{KA} = Vref, I_K = 1 mA to 100 mA		

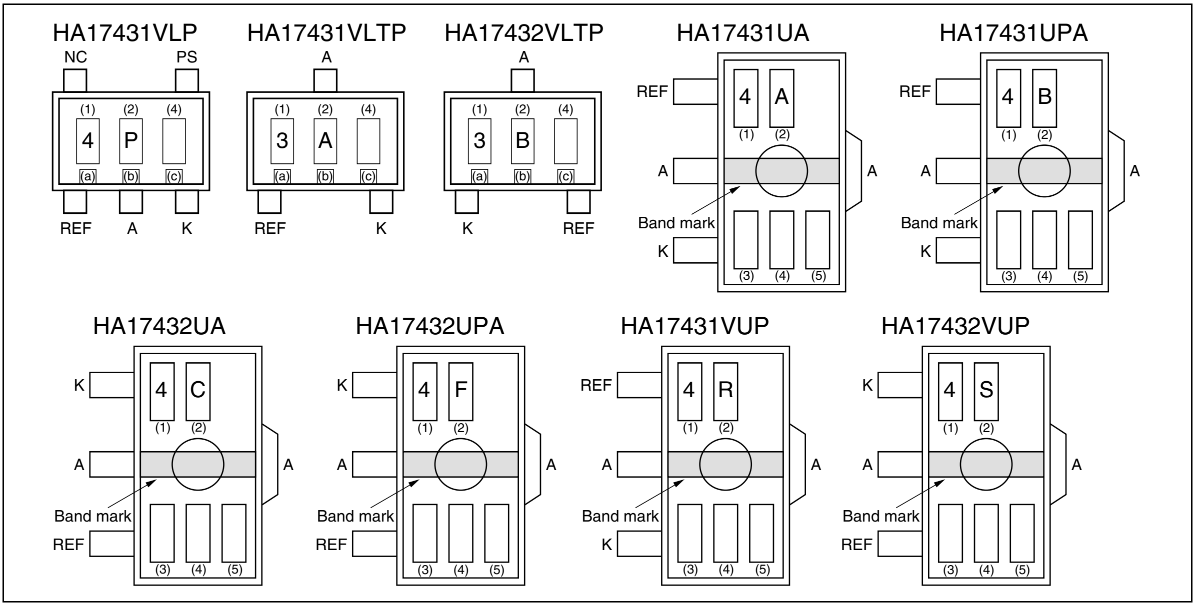
Notes: 1. Vref(dev) = Vref(max) – Vref(min)



2. Imin is given by the cathode current at Vref = $Vref_{(IK=10mA)}$ – 15 mV.
3. R_{PS} is only provided in HA17431VLP.
4. The maximum value is a design value (not measured).

MPAK-5(5-pin), MPAK(3-pin) and UPAK Marking Patterns

The marking patterns shown below are used on MPAK-5, MPAK and UPAK products. Note that the product code and mark pattern are different. The pattern is laser-printed.



Notes: 1. Boxes (1) to (5) in the figures show the position of the letters or numerals, and are not actually marked on the package.

2. The letters (1) and (2) show the product specific mark pattern.

Product	(1)	(2)
HA17431VLP	4	P
HA17431VUP	4	R
HA17432VUP	4	S
HA17431VLTP	3	A
HA17432VLTP	3	B
HA17431UA	4	A
HA17431UPA	4	B
HA17432UA	4	C
HA17432UPA	4	F

3. The letter (3) shows the production year code (the last digit of the year) for UPAK products.

4. The bars (a), (b) and (c) show a production year code for MPAK-5 and MPAK products as shown below. After 2010 the code is repeated every 8 years.

Year	2002	2003	2004	2005	2006	2007	2008	2009
(a)	None	None	None	Bar	Bar	Bar	Bar	None
(b)	None	Bar	Bar	None	None	Bar	Bar	None
(c)	Bar	None	Bar	None	Bar	None	Bar	None

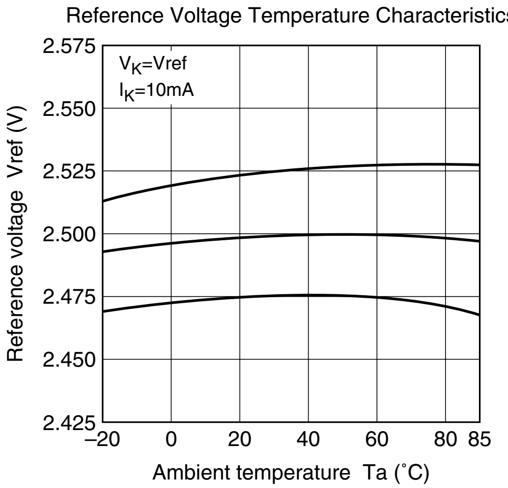
5. The letter (4) shows the production month code (see table below).

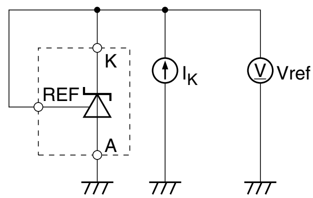
Production month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Marked code	A	B	C	D	E	F	G	H	J	K	L	M

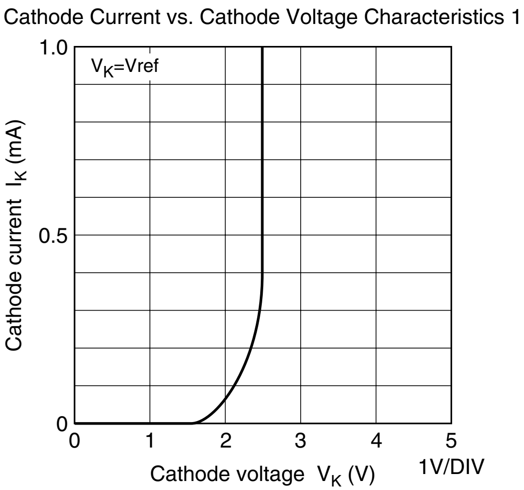
6. The letter (5) shows manufacturing code. For UPAK products.

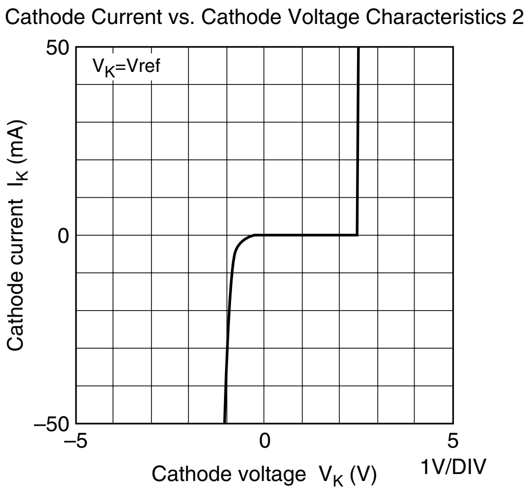
Characteristics Curves

HA17431VLP/VP/VPJ/VUP/VLTP, HA17432VUP/VLTP

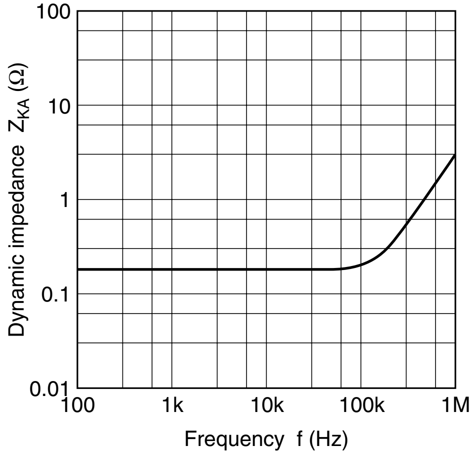


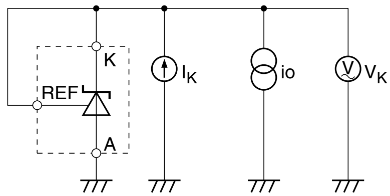






Dynamic Impedance vs. Frequency Characteristics

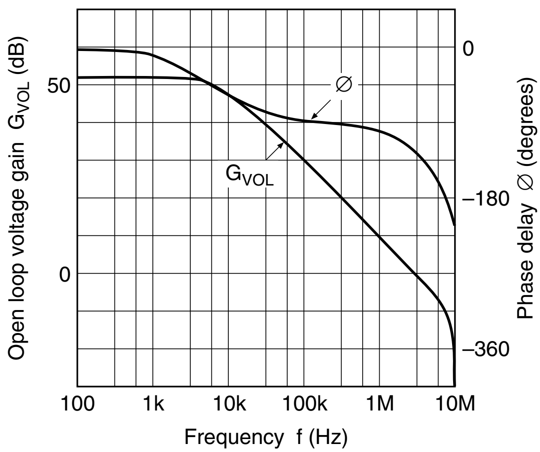


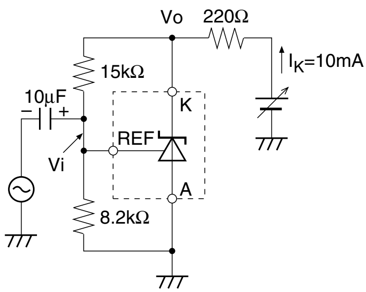


$i_O = 2\ mA_{P\text{-}P}$

$Z_{KA} = \dfrac{V_K}{i_O}\ (\Omega)$

Open Loop Voltage Gain, Phase vs. Frequency Characteristics





$G = 20\log\left(\dfrac{Vo}{Vi}\right)\ (dB)$

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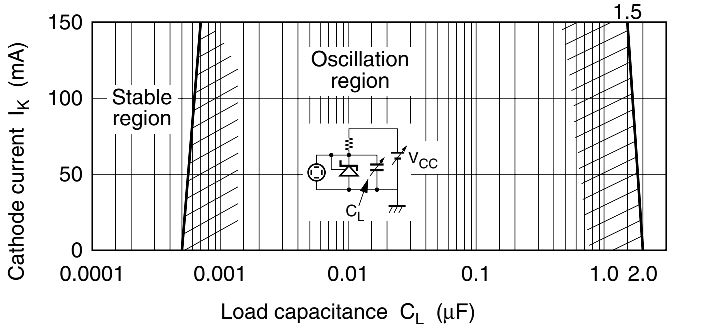
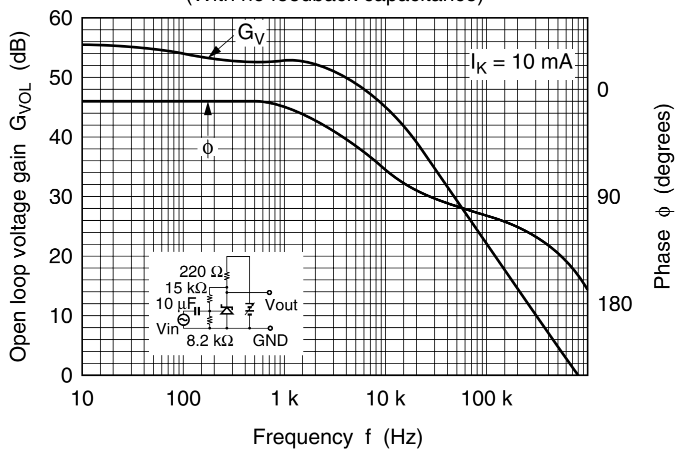
HA17431PJ/PAJ/FPJ/FPAJ/P/PA/UA/UPA/FP/FPA/PNA/PNAJ, HA17432UA/UPA

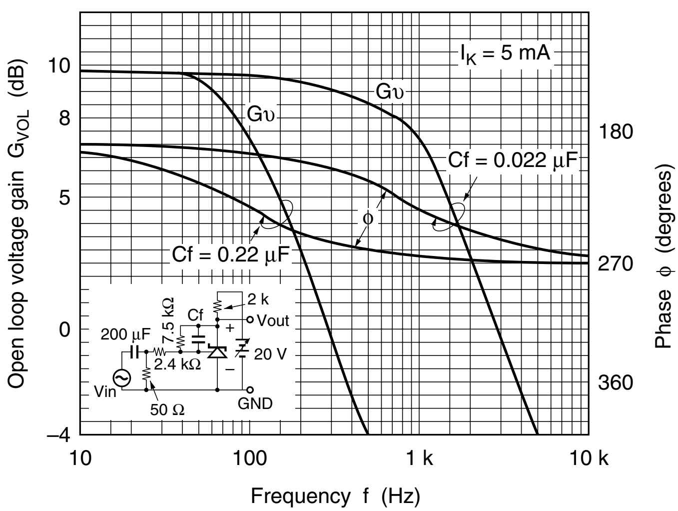
Oscillation Stability vs. Load Capacitance between Anode and Cathode

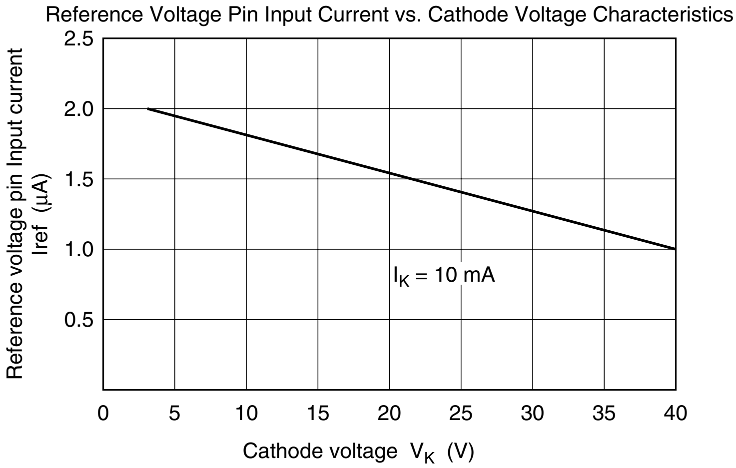


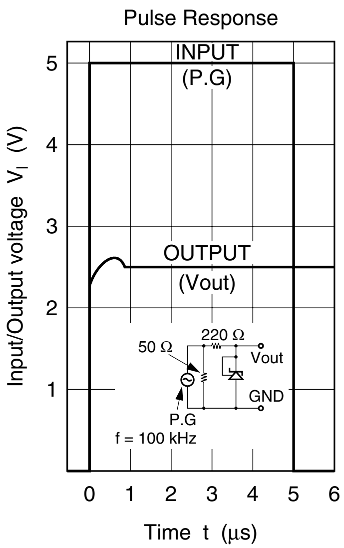
Open Loop Voltage Gain, Phase vs. Frequency Characteristics (1)
(With no feedback capacitance)

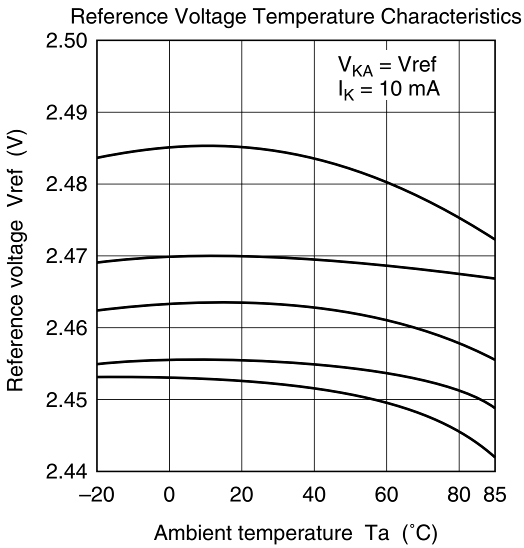


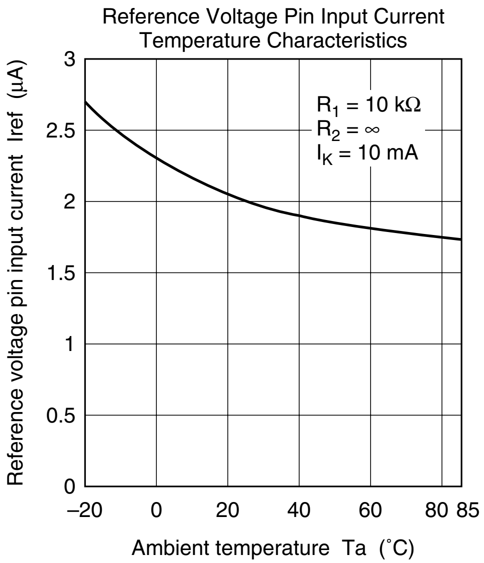
Open Loop Voltage Gain, Phase vs. Frequency Characteristics (2)
(When a feedback capacitance (Cf) is provided)

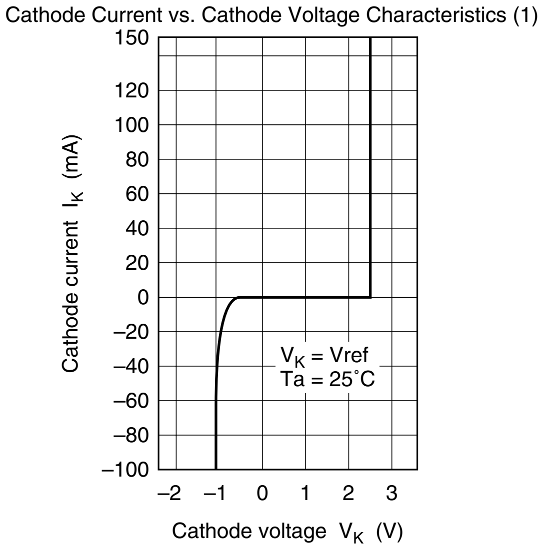


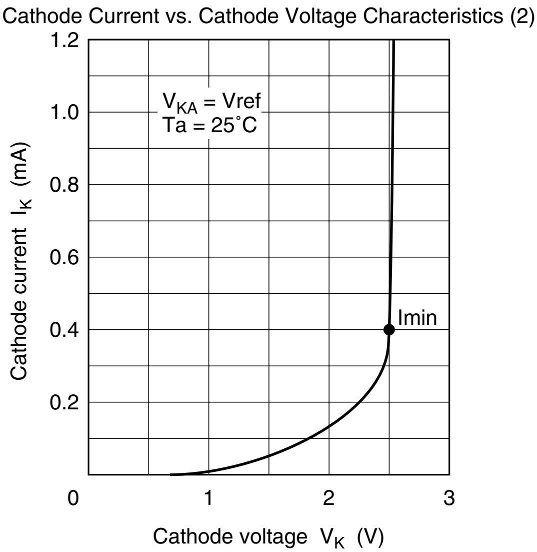

Reference Voltage Pin Input Current vs. Cathode Voltage Characteristics
Reference voltage pin Input current Iref (µA)
2.5
2.0
1.5
1.0
0.5
I_K = 10 mA
0
5
10
15
20
25
30
35
40
Cathode voltage V_K (V)

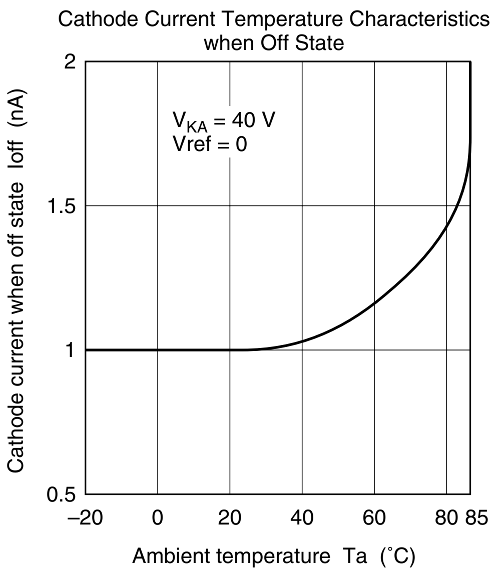

Pulse Response
Input/Output voltage V_I (V)
5
4
3
2
1
INPUT
(P.G)
OUTPUT
(Vout)
50 Ω
220 Ω
Vout
GND
P.G
f = 100 kHz
0
1
2
3
4
5
6
Time t (µs)


Reference Voltage Temperature Characteristics
Reference voltage Vref (V)
2.50
2.49
2.48
2.47
2.46
2.45
2.44
V_{KA} = Vref
I_K = 10 mA
–20
0
20
40
60
80
85
Ambient temperature Ta (˚C)


Reference Voltage Pin Input Current
Temperature Characteristics
Reference voltage pin input current Iref (µA)
R1 = 10 kΩ
R2 = ∞
IK = 10 mA
3
2.5
2
1.5
1
0.5
0
–20
0
20
40
60
80 85
Ambient temperature Ta (˚C)


Cathode Current vs. Cathode Voltage Characteristics (1)
Cathode current IK (mA)
VK = Vref
Ta = 25˚C
150
120
100
80
60
40
20
0
–20
–40
–60
–80
–100
–2
–1
0
1
2
3
Cathode voltage VK (V)


Cathode Current vs. Cathode Voltage Characteristics (2)
Cathode current IK (mA)
VKA = Vref
Ta = 25˚C
Imin
1.2
1.0
0.8
0.6
0.4
0.2
0
1
2
3
Cathode voltage VK (V)


Cathode Current Temperature Characteristics
when Off State
Cathode current when off state Ioff (nA)
VKA = 40 V
Vref = 0
2
1.5
1
0.5
–20
0
20
40
60
80 85
Ambient temperature Ta (˚C)

Application Examples

As shown in the figure on the right, this IC operates as an inverting amplifier, with the REF pin as input pin. The open-loop voltage gain is given by the reciprocal of "reference voltage deviation by cathode voltage change" in the electrical specifications, and is approximately 50 to 60 dB. The REF pin has a high input impedance, with an input current Iref of 3.8 µA Typ (V version: Iref = 2 µA Typ). The output impedance of the output pin K (cathode) is defined as dynamic impedance Z_{KA}, and Z_{KA} is low (0.2 Ω) over a wide cathode current range. A (anode) is used at the minimum potential, such as ground.

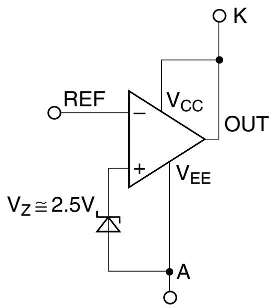
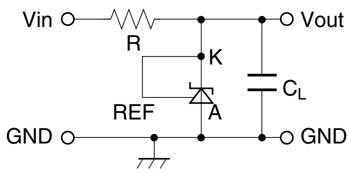
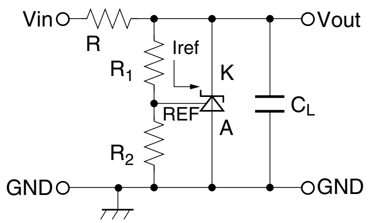


Figure 1 Operation Diagram

Application Hints

No.	Application Example	Description
1	Reference voltage generation circuit 	This is the simplest reference voltage circuit. The value of the resistance R is set so that cathode current $I_K \geq 1$ mA. Output is fixed at Vout ≅ 2.5 V. The external capacitor C_L ($C_L \geq 3.3$ µF) is used to prevent oscillation in normal applications.
2	Variable output shunt regulator circuit 	This is circuit 1 above with variable output provided. Here, $\text{Vout} \cong 2.5\ \text{V} \times \frac{(R_1 + R_2)}{R_2}$ Since the reference input current Iref = 3.8 µA Typ (V version: Iref = 2 µA Typ) flows through R_1, resistance values are chosen to allow the resultant voltage drop to be ignored.

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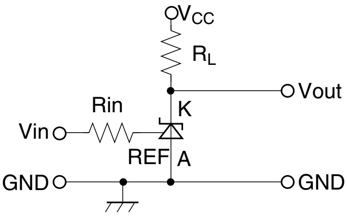
Application Hints (cont.)

No. | **Application Example** | **Description**

3 Single power supply inverting comparator circuit

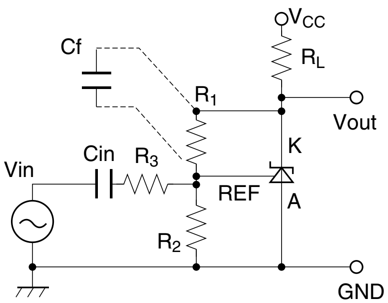


This is an inverting type comparator with an input threshold voltage of approximately 2.5 V. Rin is the REF pin protection resistance, with a value of several kΩ to several tens of kΩ.

R_L is the load resistance, selected so that the cathode current I_K • 1 mA when Vout is low.

Condition	Vin	Vout	IC
C1	Less then 2.5 V	V_{CC} (V_{OH})	OFF
C2	2.5 V or more	Approx. 2 V (V_{OL})	ON

4 AC amplifier circuit



$$\text{Gain } G = \frac{R_1}{R_2 \mathbin{//} R_3} \text{ (DC gain)}$$

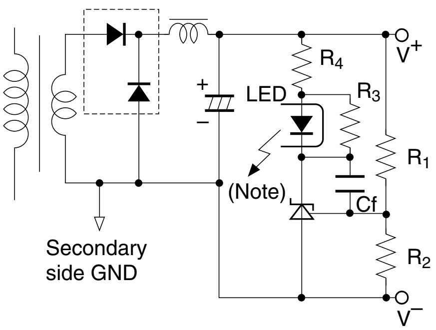
$$\text{Cutoff frequency } fc = \frac{1}{2\pi \, Cf \, (R_1 \mathbin{//} R_2 \mathbin{//} R_3)}$$

This is an AC amplifier with voltage gain $G = -R_1 / (R_2//R_3)$. The input is cut by capacitance Cin, so that the REF pin is driven by the AC input signal, centered on 2.5 V_{DC}.

R_2 also functions as a resistance that determines the DC cathode potential when there is no input, but if the input level is low and there is no risk of Vout clipping to V_{CC}, this can be omitted.

To change the frequency characteristic, Cf should be connected as indicated by the dotted line.

5 Switching power supply error amplification circuit



Note: LED : Light emitting diode in photocoupler
R3 : Bypass resistor to feed IK(>Imin) when LED current vanishes
R4 : LED protection resistance

This circuit performs control on the secondary side of a transformer, and is often used with a switching power supply that employs a photocoupler for offlining.

The output voltage (between V+ and V–) is given by the following formula:

$$\text{Vout} \cong 2.5 \text{ V} \times \frac{(R_1 + R_2)}{R_2}$$

In this circuit, the gain with respect to the Vout error is as follows:

$$G = \frac{R_2}{(R_1 + R_2)} \times \left[\begin{array}{l}\text{HA17431 open}\\ \text{loop gain}\end{array}\right] \times \left[\begin{array}{l}\text{photocoupler}\\ \text{total gain}\end{array}\right]$$

As stated earlier, the HA17431 open-loop gain is 50 to 60 dB.

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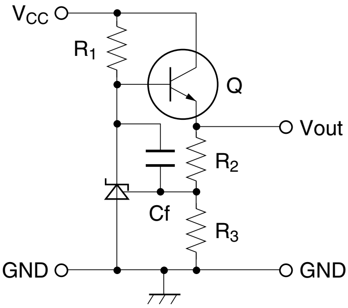
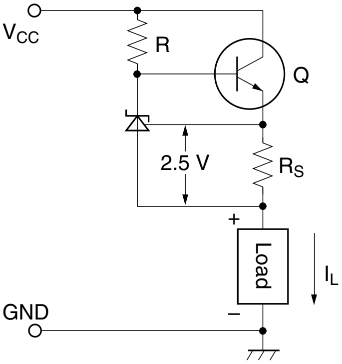
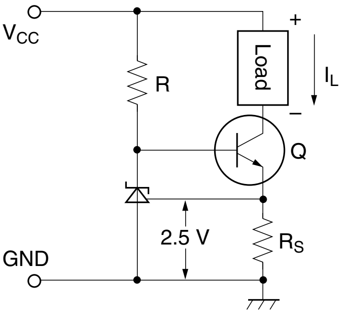
Application Hints (cont.)

No.	Application Example	Description
6	Constant voltage regulator circuit 	This is a 3-pin regulator with a discrete configuration, in which the output voltage $$Vout = 2.5\ V \times \frac{(R_2 + R_3)}{R_3}$$ R_1 is a bias resistance for supplying the HA17431 cathode current and the output transistor Q base current.
7	Discharge type constant current circuit 	This circuit supplies a constant current of $I_L \cong \frac{2.5\ V}{R_S}$ [A] into the load. Caution is required since the HA17431 cathode current is also superimposed on I_L. The requirement in this circuit is that the cathode current must be greater than Imin = 1 mA. The I_L setting therefore must be on the order of several mA or more.
8	Induction type constant current circuit 	In this circuit, the load is connected on the collector side of transistor Q in circuit 7 above. In this case, the load floats from GND, but the HA17431 cathode current is not superimposed on I_L, so that I_L can be kept small (1 mA or less is possible). The constant current value is the same as for circuit 7 above: $I_L \cong \frac{2.5\ V}{R_S}$ [A]

Design Guide for AC-DC SMPS (Switching Mode Power Supply)

Use of Shunt Regulator in Transformer Secondary Side Control

This example is applicable to both forward transformers and flyback transformers. A shunt regulator is used on the secondary side as an error amplifier, and feedback to the primary side is provided via a photocoupler.

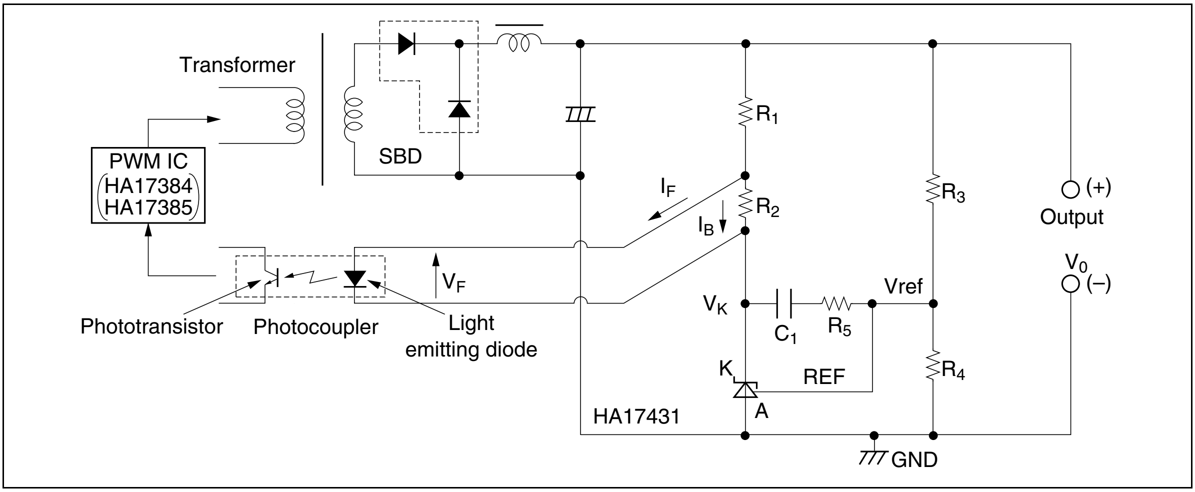


Figure 2 Typical Shunt Regulator/Error Amplifier

Determination of External Constants for the Shunt Regulator

DC characteristic determination: In figure 2, R_1 and R_2 are protection resistor for the light emitting diode in the photocoupler, and R_2 is a bypass resistor to feed I_K minimum, and these are determined as shown below. The photocoupler specification should be obtained separately from the manufacturer. Using the parameters in figure 2, the following formulas are obtained:

$$R_1 = \frac{V_0 - V_F - V_K}{I_F + I_B}, \quad R_2 = \frac{V_F}{I_B}$$

V_K is the HA17431 operating voltage, and is set at around 3 V, taking into account a margin for fluctuation. R_2 is the current shunt resistance for the light emitting diode, in which a bias current I_B of around 1/5 I_F flows.

Next, the output voltage can be determined by R3 and R4, and the following formula is obtained:

$$V_0 = \frac{R_3 + R_4}{R_4} \times \text{Vref}, \text{ Vref} = 2.5\text{ V Typ}$$

The absolute values of R_3 and R_4 are determined by the HA17431 reference input current Iref and the AC characteristics described in the next section. The Iref value is around 3.8 µA Typ. (V version: 2 µA Typ)

AC characteristic determination: This refers to the determination of the gain frequency characteristic of the shunt regulator as an error amplifier. Taking the configuration in figure 2, the error amplifier characteristic is as shown in figure 3.

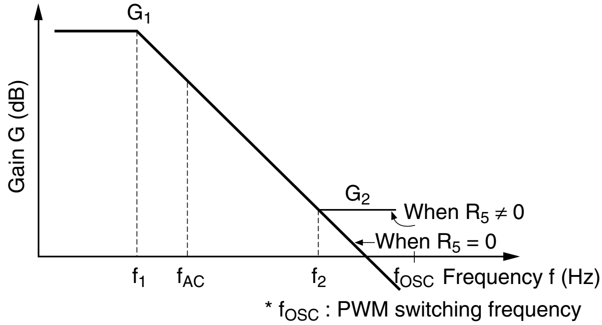


Figure 3 HA17431 Error Amplification Characteristic

In Figure 3, the following formulas are obtained:

Gain

$G_1 = G_0 \approx 50$ dB to 60 dB (determined by shunt regulator)

$$G_2 = \frac{R_5}{R_3}$$

Corner frequencies

$f_1 = 1/(2\pi\ C_1\ G_0\ R_3)$

$f_2 = 1/(2\pi\ C_1\ R_5)$

G_0 is the shunt regulator open-loop gain; this is given by the reciprocal of the reference voltage fluctuation $\Delta Vref/\Delta V_{KA}$, and is approximately 50 dB.

Practical Example

Consider the example of a photocoupler, with an internal light emitting diode V_F = 1.05 V and I_F = 2.5 mA, power supply output voltage V_2 = 5 V, and bias resistance R_2 current of approximately 1/5 I_F at 0.5 mA. If the shunt regulator V_K = 3 V, the following values are found.

$$R_1 = \frac{5V - 1.05V - 3V}{2.5mA + 0.5mA} = 316(\Omega)\ (330\Omega \text{ from E24 series})$$

$$R_2 = \frac{1.05V}{0.5mA} = 2.1(k\Omega)\ (2.2k\Omega \text{ from E24 series})$$

Next, assume that $R_3 = R_4$ = 10 kΩ. This gives a 5 V output. If R_5 = 3.3 kΩ and C_1 = 0.022 µF, the following values are found.

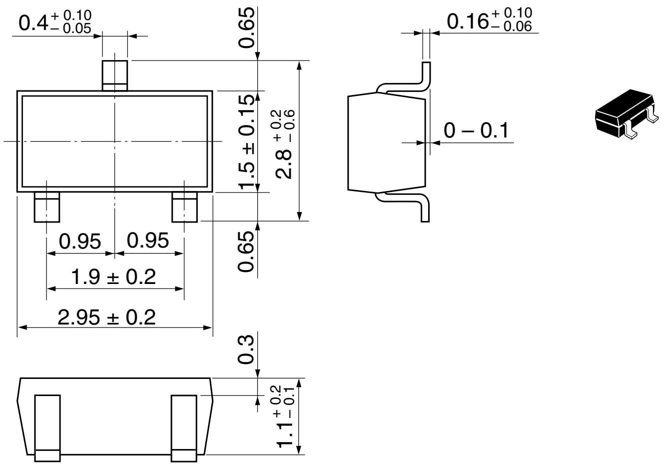
G_2 = 3.3 kΩ / 10 kΩ = 0.33 times (–10 dB)

f_1 = 1 / (2 × π × 0.022 µF × 316 × 10 kΩ) = 2.3 (Hz)

f_2 = 1 / (2 × π × 0.022 µF × 3.3 kΩ) = 2.2 (kHz)

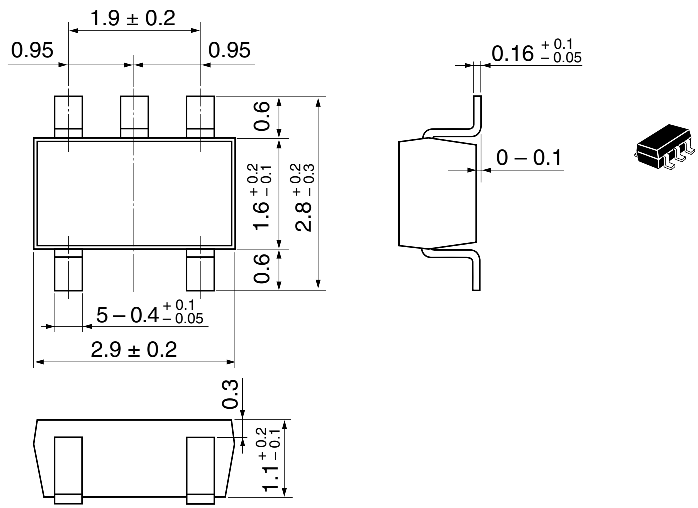
Package Dimensions

As of January, 2002
Unit: mm



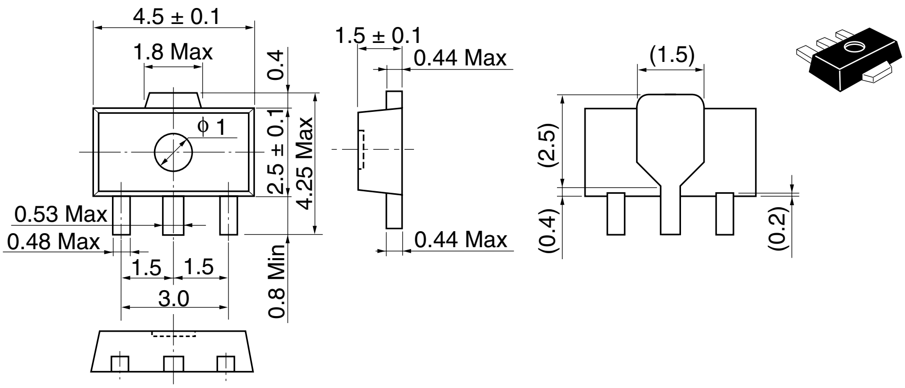
Hitachi Code	MPAK
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.011 g

As of January, 2002
Unit: mm



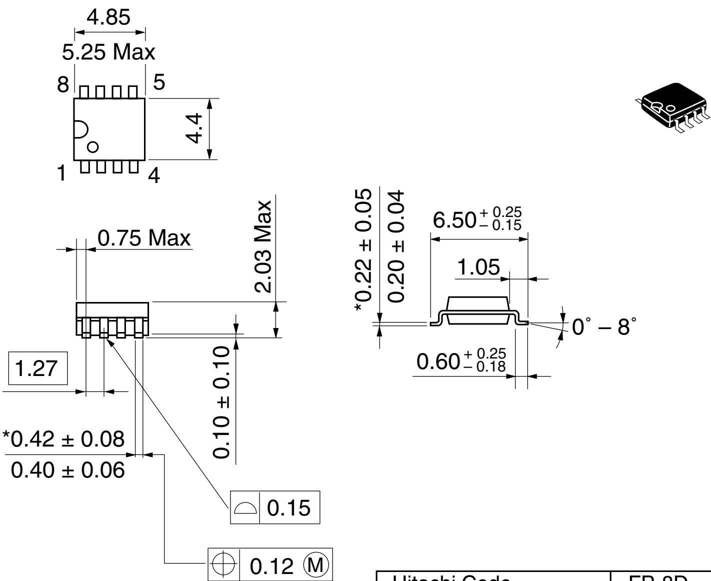
Hitachi Code	MPAK-5
JEDEC	—
JEITA	—
Mass (reference value)	0.015 g

As of January, 2002
Unit: mm



Hitachi Code	UPAK
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.050 g

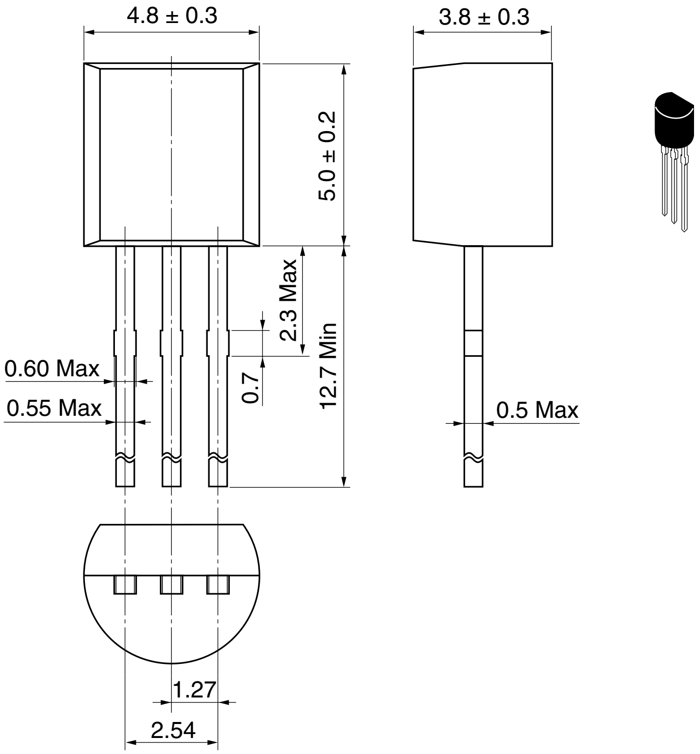
As of January, 2002
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-8D
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.10 g

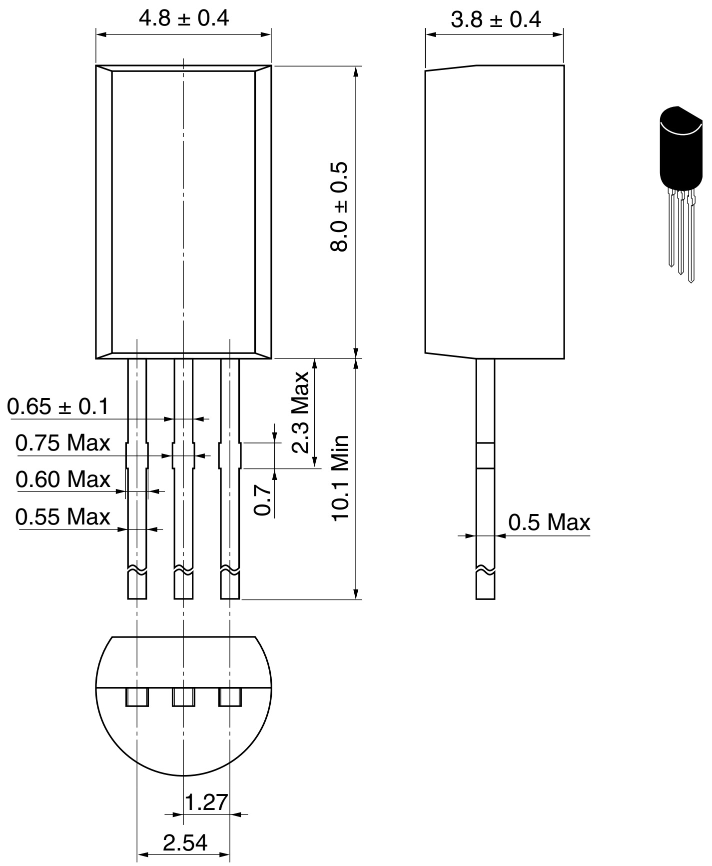
As of January, 2002
Unit: mm



Hitachi Code	TO-92 (1)
JEDEC	Conforms
JEITA	Conforms
Mass (reference value)	0.25 g

As of January, 2002

Unit: mm



Hitachi Code	TO-92 Mod
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.35 g

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